

DATA SHEET

NEC

MOS FIELD EFFECT TRANSISTOR 2SK3901

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3901 is N-channel MOS Field Effect Transistor designed for high current switching applications.

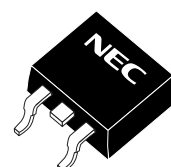
ORDERING INFORMATION

| PART NUMBER | PACKAGE |
|-------------|------------------|
| 2SK3901-ZK | TO-263 (MP-25ZK) |

FEATURES

- Super low On-state resistance
 $R_{DS(on)1} = 13 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 30 \text{ A)}$
 $R_{DS(on)2} = 16.5 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.5 \text{ V, } I_D = 30 \text{ A)}$
- Low C_{iss} : $C_{iss} = 1950 \text{ pF TYP.}$
- Built-in gate protection diode

(TO-263)



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

| | | | |
|--|----------------|------------------------|------------------|
| Drain to Source Voltage ($V_{GS} = 0 \text{ V}$) | V_{DSS} | 60 | V |
| Gate to Source Voltage ($V_{DS} = 0 \text{ V}$) | V_{GSS} | ± 20 | V |
| Drain Current (DC) ($T_C = 25^\circ\text{C}$) | $I_{D(DC)}$ | ± 60 | A |
| Drain Current (pulse) ^{Note1} | $I_{D(pulse)}$ | ± 150 | A |
| Total Power Dissipation ($T_C = 25^\circ\text{C}$) | P_{T1} | 64 | W |
| Total Power Dissipation ($T_A = 25^\circ\text{C}$) | P_{T2} | 1.5 | W |
| Channel Temperature | T_{ch} | 150 | $^\circ\text{C}$ |
| Storage Temperature | T_{stg} | $-55 \text{ to } +150$ | $^\circ\text{C}$ |
| Single Avalanche Energy ^{Note2} | E_{AS} | 68 | mJ |
| Repetitive Avalanche Current ^{Note3} | I_{AR} | 26 | A |
| Repetitive Avalanche Energy ^{Note3} | E_{AR} | 68 | mJ |

Notes 1. $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1\%$

2. Starting $T_{ch} = 25^\circ\text{C}$, $V_{DD} = 30 \text{ V}$, $R_G = 25 \Omega$, $V_{GS} = 20 \rightarrow 0 \text{ V}$, $L = 100 \mu\text{H}$

3. $R_G = 25 \Omega$, $T_{ch(peak)} \leq 150^\circ\text{C}$

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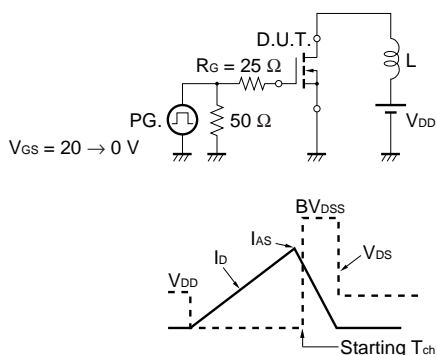
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ELECTRICAL CHARACTERISTICS (T_A = 25°C)

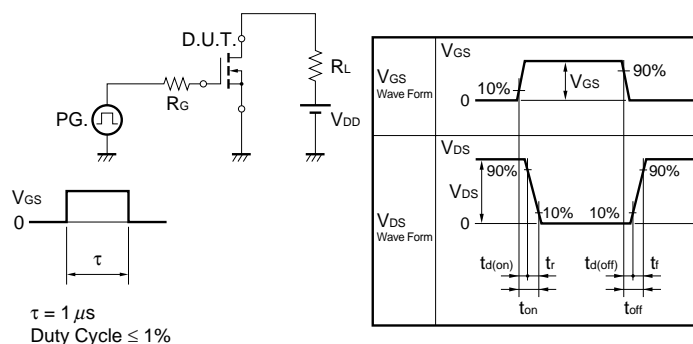
| CHARACTERISTICS | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---|----------------------|--|------|------|------|------|
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} = 60 V, V _{GS} = 0 V | | | 10 | μA |
| Gate Leakage Current | I _{GSS} | V _{GS} = ±20 V, V _{DS} = 0 V | | | ±10 | μA |
| Gate Cut-off Voltage | V _{GS(off)} | V _{DS} = 10 V, I _D = 1 mA | 1.5 | 2.0 | 2.5 | V |
| Forward Transfer Admittance ^{Note} | y _{fs} | V _{DS} = 10 V, I _D = 30 A | 18 | 36 | | S |
| Drain to Source On-state Resistance ^{Note} | R _{DS(on)1} | V _{GS} = 10 V, I _D = 30 A | | 10.3 | 13 | mΩ |
| | R _{DS(on)2} | V _{GS} = 4.5 V, I _D = 30 A | | 12.1 | 16.5 | mΩ |
| Input Capacitance | C _{iss} | V _{DS} = 10 V | | 1950 | | pF |
| Output Capacitance | C _{oss} | V _{GS} = 0 V | | 380 | | pF |
| Reverse Transfer Capacitance | C _{rss} | f = 1 MHz | | 150 | | pF |
| Turn-on Delay Time | t _{d(on)} | V _{DD} = 30 V, I _D = 30 A | | 12 | | ns |
| Rise Time | t _r | V _{GS} = 10 V | | 6 | | ns |
| Turn-off Delay Time | t _{d(off)} | R _G = 0 Ω | | 48 | | ns |
| Fall Time | t _f | | | 5.0 | | ns |
| Total Gate Charge | Q _G | V _{DD} = 48 V | | 40 | | nC |
| Gate to Source Charge | Q _{GS} | V _{GS} = 10 V | | 7.5 | | nC |
| Gate to Drain Charge | Q _{GD} | I _D = 60 A | | 10.0 | | nC |
| Body Diode Forward Voltage ^{Note} | V _{F(S-D)} | I _F = 60 A, V _{GS} = 0 V | | 0.96 | 1.5 | V |
| Reverse Recovery Time | t _{rr} | I _F = 60 A, V _{GS} = 0 V | | 32 | | ns |
| Reverse Recovery Charge | Q _{rr} | di/dt = 100 A/μs | | 45 | | nC |

Note Pulsed

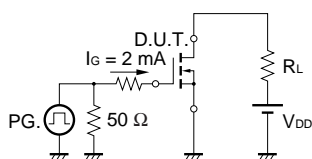
TEST CIRCUIT 1 AVALANCHE CAPABILITY



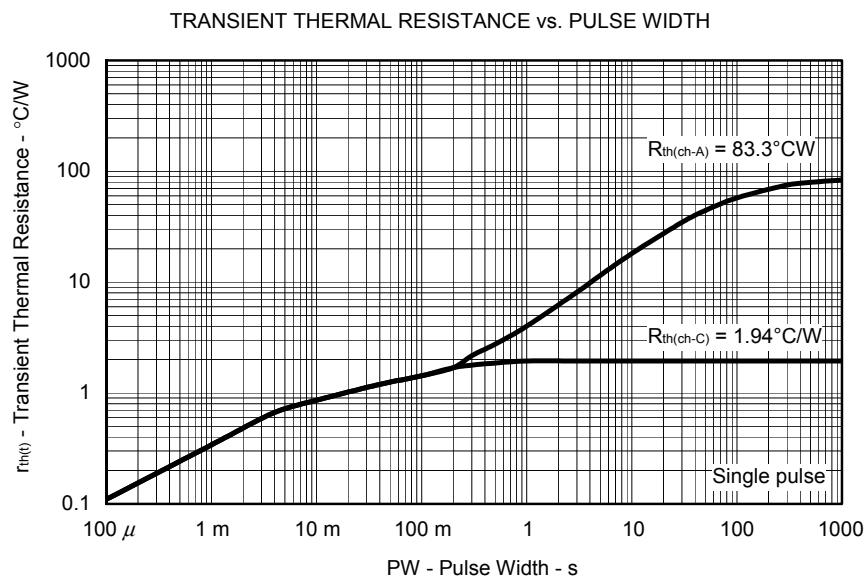
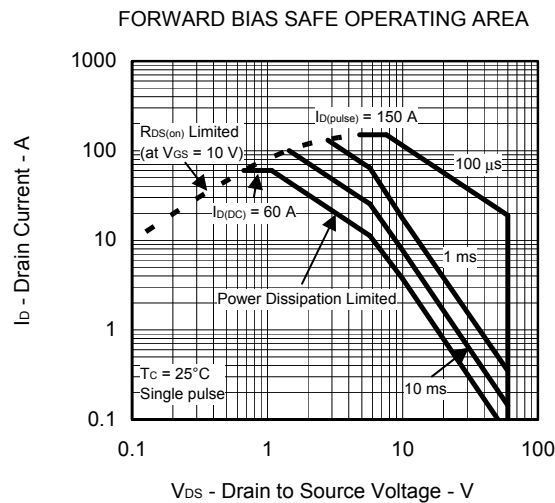
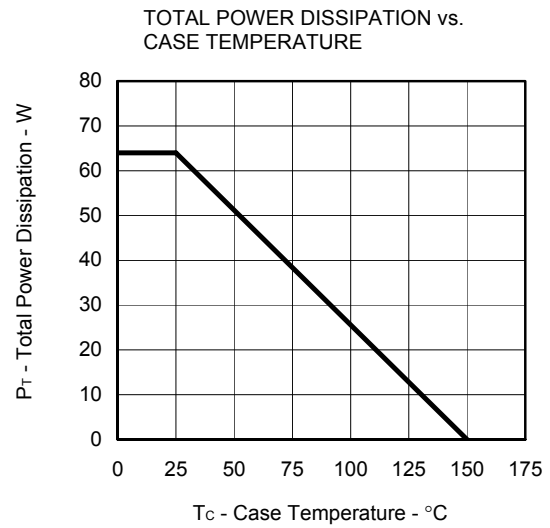
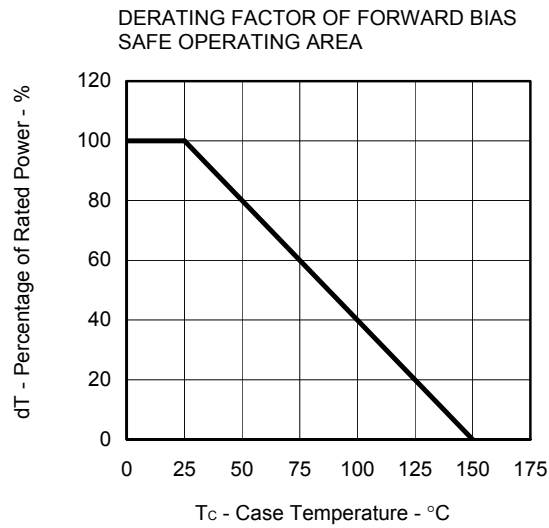
TEST CIRCUIT 2 SWITCHING TIME



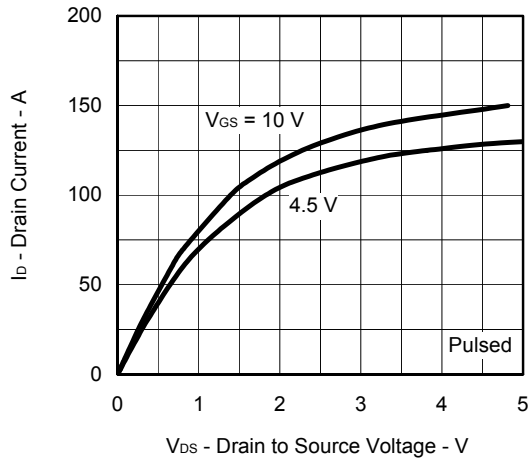
TEST CIRCUIT 3 GATE CHARGE



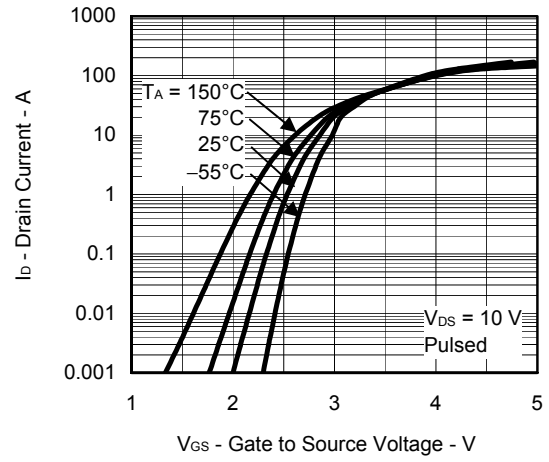
TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)



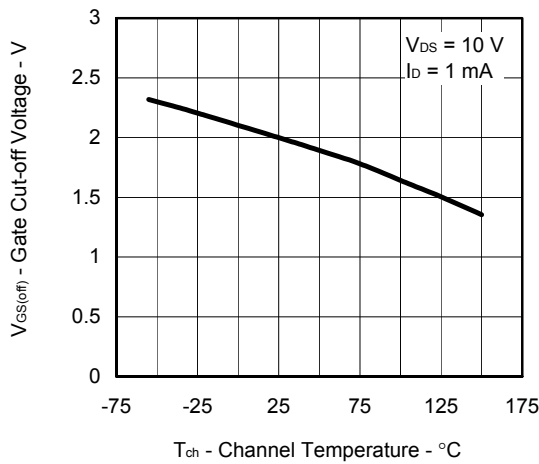
DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



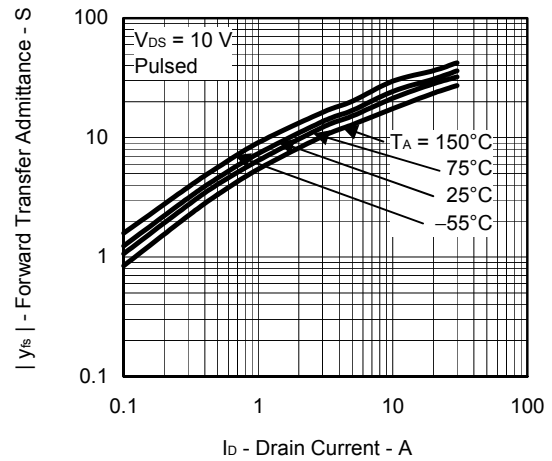
FORWARD TRANSFER CHARACTERISTICS



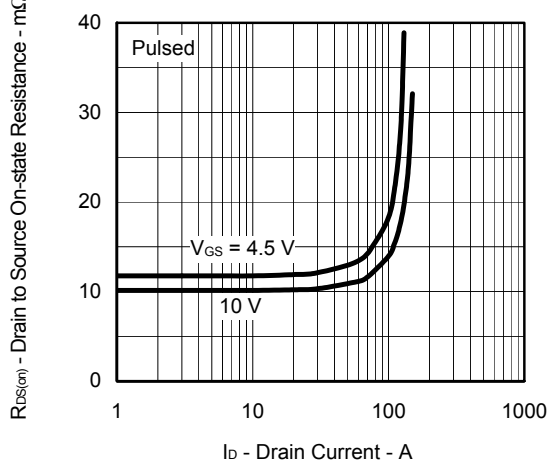
GATE CUT-OFF VOLTAGE vs.
CHANNEL TEMPERATURE



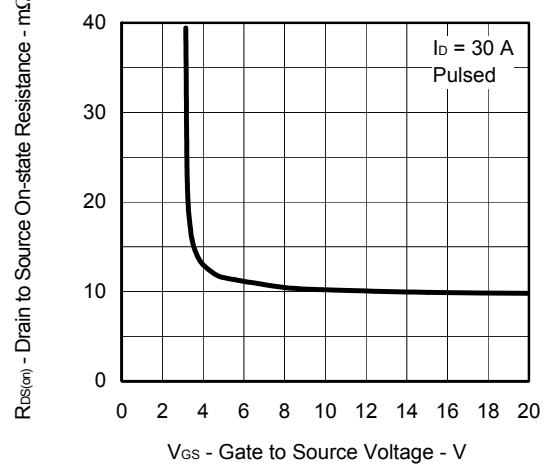
FORWARD TRANSFER ADMITTANCE vs.
DRAIN CURRENT

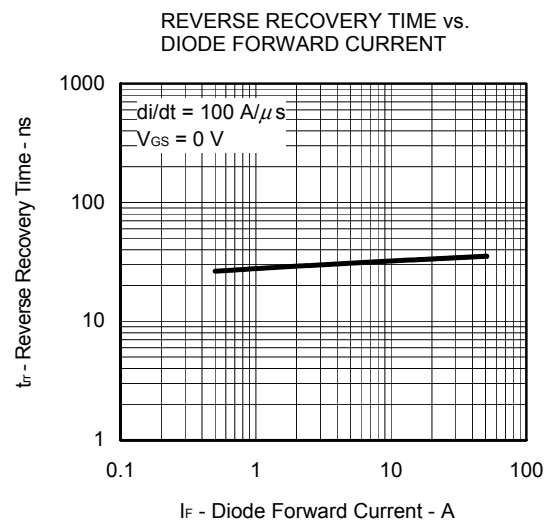
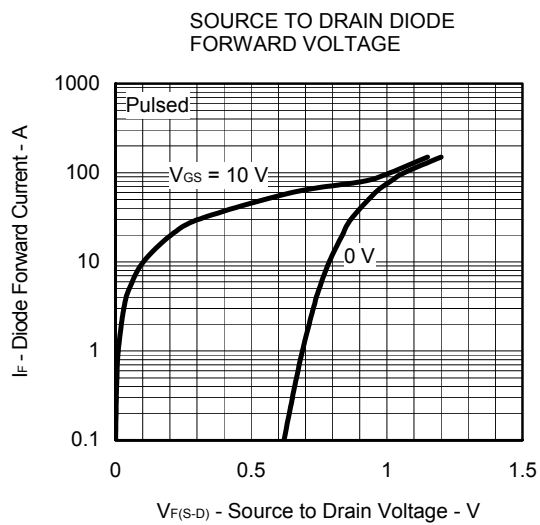
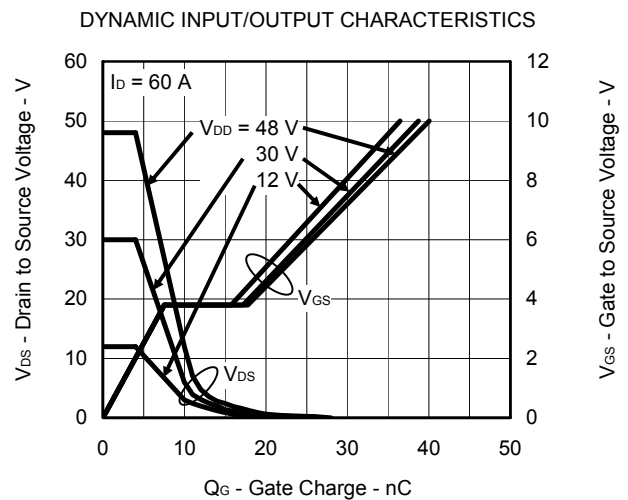
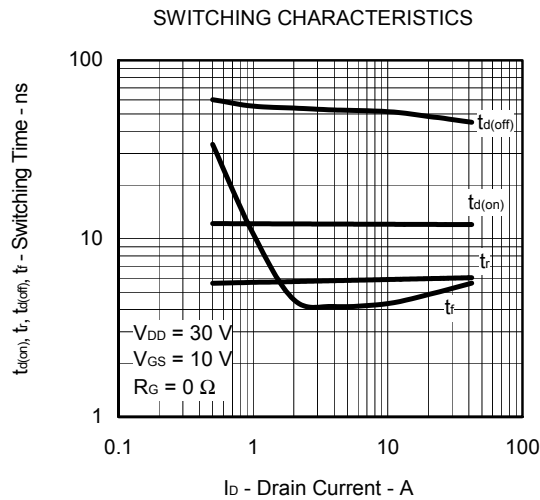
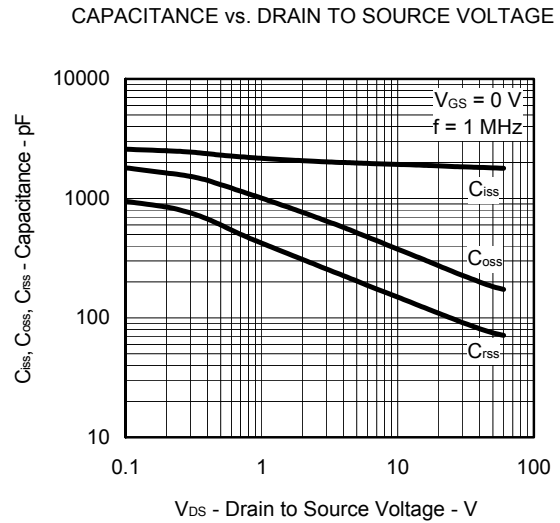
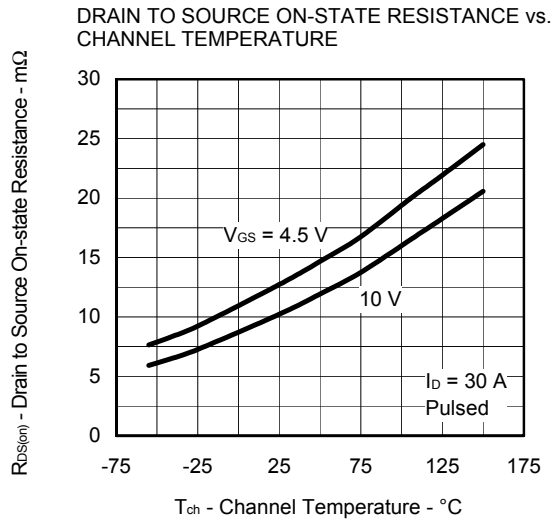


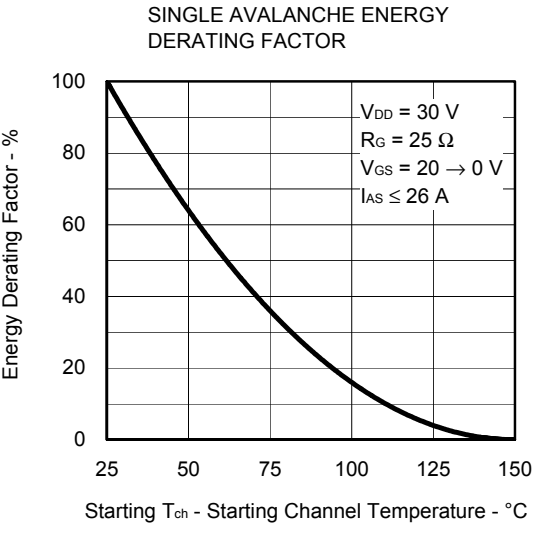
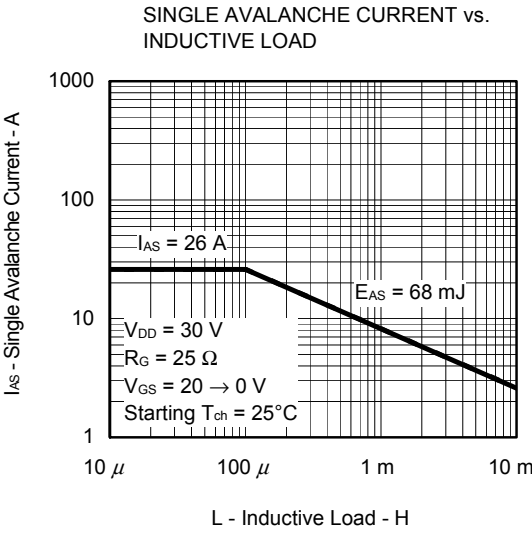
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs.
GATE TO SOURCE VOLTAGE

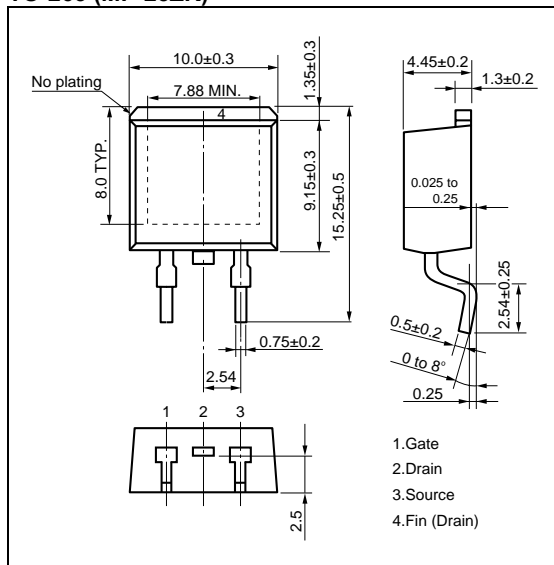




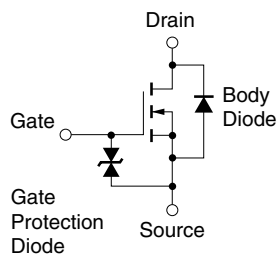


PACKAGE DRAWING (Unit: mm)

TO-263 (MP-25ZK)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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